
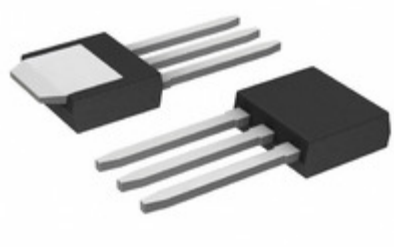





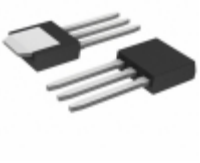


	<p><b>NTD95N02R-1G</b></p>
	<p><b>Hersteller-Teilenummer:</b> NTD95N02R-1G</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 24V 12A IPAK</p> <p><b>Datenblätter:</b>  <a href="#">NTD95N02R-1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 5000 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	NTD95N02R-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 24V 12A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.25W (Ta), 86W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	24V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	12A (Ta), 32A (Tc)
Rds On (Max) @ Id, Vgs	5 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	21nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2400pF @ 20V
Verpackung	Tube

NTD95N02R-1G ist neu im Original, Suche NTD95N02R-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD95N02R-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD95N02R-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>NTD95N02-001</b> VB NTD95N02-001 VB</p>	 <p><b>NTD95N02RT4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12A DPAK</p>	 <p><b>NTD95N02-1G</b> VB NTD95N02-1G VB</p>	 <p><b>NTD95N02R</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12A DPAK</p>
 <p><b>NTD95N02RT4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12A DPAK</p>	 <p><b>NTD95N02R-001</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12A IPAK</p>	 <p><b>NTDN</b> Apex Tool Group TIP CHISEL NTD</p>	 <p><b>NTD85N02T4G</b> ON NTD85N02T4G ON</p>

### heiße Teile

Mehr

NTD70N03	NTD70N03R	NTD70N03R-001	NTD70N03R-1	NTD70N03R-1G
NTD70N03RG	NTD70N03RT4	NTD70N03RT4G	NTD70N03TR4	NTD78N03
NTD78N03-001	NTD78N03-035	NTD78N03-1	NTD78N03-1G	NTD78N03-35G
NTD78N03R-001	NTD78N03R-1G	NTD78N03RT4G	NTD78N03T4	NTD78N03T4G
NTD80N02	NTD80N02-001	NTD80N02-1	NTD80N02-1G	NTD80N02G
NTD80N02T4	NTD80N02T4G	NTD85N02-1G	NTD85N02R	NTD85N02R-001
NTD85N02R-1	NTD85N02R-1G	NTD85N02R14	NTD85N02RG	NTD85N02RT4G
NTD85N02T4G	NTD95N02-001	NTD95N02-1G	NTD95N02R	NTD95N02RG
NTD95N02RT4G	NTDV18N06LT4G	NTDV20N06LT4G	NTDV20N06T4G	NTDV20P06LT4G
NTDV20P06LT4G	NTDV2955PT4G	NTDV3055L104T4G	NTDV5804NT4G	NTDV5805NT4G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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